Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1905	(430/1 or 430/2 or 359/3 or 359/12). ccls.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/16 15:32
L2	38	l1 and (pdlc or ((polymer near5 dispersed) near5 (lc or crystal\$1)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/16 15:34
L3	5	(copy or copying or copied or (contact near5 expos\$6)) and I2	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/08/16 15:35

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$%^STN;HighlightOn= ***;HighlightOff=***
Connecting via Winsock to STN
Welcome to STN International! Enter x:x
LOGINID:ssspta1756mja
PASSWORD:
TERMINAL (ENTER 1, 2, 3, OR ?):2
                      Welcome to STN International
 NEWS
      1
                  Web Page URLs for STN Seminar Schedule - N. America
 NEWS
                  "Ask CAS" for self-help around the clock
 NEWS 3 FEB 28
                  PATDPAFULL - New display fields provide for legal status
                  data from INPADOC
 NEWS
      4 FEB 28 BABS - Current-awareness alerts (SDIs) available
 NEWS 5 MAR 02 GBFULL: New full-text patent database on STN
 NEWS 6 MAR 03 REGISTRY/ZREGISTRY - Sequence annotations enhanced
 NEWS
     10 MAR 22
 NEWS
 NEWS
                  fields
      13 APR 04
 NEWS
 NEWS
      14 APR 18
 NEWS
      15 APR 25
                  applications.
 NEWS
      16 APR 28
                  U.S. patent records in CA/CAplus
 NEWS
      17 MAY 23
 NEWS
      18 MAY 23
                  CHEMCATS
 NEWS
      19 JUN 06
                  (Version 8.0 for Windows) now available
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NEWS 7 MAR 03 MEDLINE file segment of TOXCENTER reloaded
NEWS 8 MAR 22 KOREAPAT now updated monthly; patent information enhanced
NEWS 9 MAR 22 Original IDE display format returns to REGISTRY/ZREGISTRY
                PATDPASPC - New patent database available
     11 MAR 22 REGISTRY/ZREGISTRY enhanced with experimental property tags
     12 APR 04 EPFULL enhanced with additional patent information and new
                EMBASE - Database reloaded and enhanced
                New CAS Information Use Policies available online
                Patent searching, including current-awareness alerts (SDIs),
                 based on application date in CA/CAplus and USPATFULL/USPAT2
                 may be affected by a change in filing date for U.S.
                 Improved searching of U.S. Patent Classifications for
                 GBFULL enhanced with patent drawing images
                REGISTRY has been enhanced with source information from
                The Analysis Edition of STN Express with Discover!
NEWS
      20 JUN 13
                RUSSIAPAT: New full-text patent database on STN
NEWS
      21 JUN 13
                FRFULL enhanced with patent drawing images
                MARPAT displays enhanced with expanded G-group definitions
NEWS
     22 JUN 27
                 and text labels
NEWS
      23 JUL 01
                MEDICONF removed from STN
                STN Patent Forums to be held in July 2005
NEWS
      24 JUL 07
NEWS
      25 JUL 13
                 SCISEARCH reloaded
                Powerful new interactive analysis and visualization software,
NEWS
      26 JUL 20
                 STN AnaVist, now available
NEWS
      27 AUG 11
                Derwent World Patents Index(R) web-based training during
                 August
      28 AUG 11
NEWS
                STN AnaVist workshops to be held in North America
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NEWS HOURS STN Operating Hours Plus Help Desk Availability NEWS INTER General Internet Information NEWS LOGIN Welcome Banner and News Items Direct Dial and Telecommunication Network Access to STN NEWS PHONE CAS World Wide Web Site (general information) NEWS WWW

JUNE 13 CURRENT WINDOWS VERSION IS V8.0, CURRENT MACINTOSH VERSION IS V6.0c(ENG) AND V6.0Jc(JP), AND CURRENT DISCOVER FILE IS DATED 13 JUNE 2005

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SINCE FILE TOTAL ENTRY SESSION 0.21 0.21

FULL ESTIMATED COST

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This file contains CAS Registry Numbers for easy and accurate substance identification.

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(pdlc or ((polymer(4a)dispers?)(5a)(lc or lcd or (liquid(4a)crystal))))
           819 PDLC
           169 PDLCS
           884 PDLC
                  (PDLC OR PDLCS)
       1020028 POLYMER
        840995 POLYMERS
       1381077 POLYMER
                  (POLYMER OR POLYMERS)
        604841 DISPERS?
         32805 LC
          1228 LCS
         33413 LC
                  (LC OR LCS)
         11200.LCD
          1147 LCDS
         11697 LCD
                  (LCD OR LCDS)
        691088 LIQUID
        123676 LIQUIDS
        784645 LIQUID
                  (LIQUID OR LIQUIDS)
        964955 LIQ
         92015 LIQS
       1000835 LIQ
                  (LIQ OR LIQS)
       1384151 LIQUID
                  (LIQUID OR LIQ)
       1171264 CRYSTAL
        617496 CRYSTALS
       1444992 CRYSTAL
                  (CRYSTAL OR CRYSTALS)
          2529 (POLYMER (4A) DISPERS?) (5A) (LC OR LCD OR (LIQUID (4A) CRYSTAL))
L1
          2603 (PDLC OR ((POLYMER(4A)DISPERS?)(5A)(LC OR LCD OR (LIQUID(4A)CRYS
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TAL))))

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         2863 COPIED
        29897 MASTER?
       445801 CONTACT
       108018 CONTACTS
       501678 CONTACT
                (CONTACT OR CONTACTS)
       761304 EXPOS?
         6694 CONTACT (5A) EXPOS?
            5 (COPY? OR COPIED OR MASTER? OR (CONTACT(5A)EXPOS?)) AND L1
L2
=> s (copy? or copied or master? or duplicat? or (contact(5a)expos?)) and l1
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        29897 MASTER?
        32531 DUPLICAT?
       445801 CONTACT
       108018 CONTACTS
       501678 CONTACT
                (CONTACT OR CONTACTS)
       761304 EXPOS?
         6694 CONTACT (5A) EXPOS?
            5 (COPY? OR COPIED OR MASTER? OR DUPLICAT? OR (CONTACT(5A)EXPOS?))
L3
=> d all 1-5
    ANSWER 1 OF 5 CAPLUS COPYRIGHT 2005 ACS on STN
L3
    2004:360257 CAPLUS
DN
    140:383146
ED
    Entered STN: 04 May 2004
ΤI
    System and method for replicating volume holograms
    Sutherland, Richard L.; Sappington, John; Brandelik, Donna M.; Siwecki,
    Stephen A.; Shepherd, Christina K.; Pogue, Robert T.
    Science Applications International Corporation, USA
PA
    U.S., 29 pp.
    CODEN: USXXAM
DT
    Patent
    English
LA
     ICM G03H001-02
IC
INCL 430001000; 430002000; 359012000; 359003000
     74-8 (Radiation Chemistry, Photochemistry, and Photographic and Other
     Reprographic Processes)
FAN.CNT 1
    PATENT NO.
                       KIND
                              DATE
                                        APPLICATION NO.
                                                               DATE
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                                         ______
                                                               _____
                                       US 2000-577166
    US 6730442
                       B1
                              20040504
                                                               20000524
    US 2004175627
                       A1
                              20040909
                                         US 2004-796071
                                                               20040310
PRAI US 2000-577166
                       A1
                              20000524
                CLASS PATENT FAMILY CLASSIFICATION CODES
 PATENT NO.
                ____
                ICM
                      G03H001-02
 US 6730442
                INCL
                       430001000; 430002000; 359012000; 359003000
 US 6730442
                NCL
                       430/001.000; 359/003.000; 359/012.000; 430/002.000
                ECLA
                       G02F001/1334H; G03H001/04F; G03H001/20; G03H001/28
 US 2004175627
                NCL
                       430/001.000
                      G02F001/1334H; G03H001/04F; G03H001/20; G03H001/28
                ECLA
AB
     The present invention offers increased efficiency and quality in the
       ***duplication*** of a ***master*** hologram utilizing an improved
     method of contact printing. This improved method of contact printing
                ***polymer*** - ***dispersed***
                                                  ***liq***
       ***crystal*** ( ***PDLC*** ) recording medium as the
       ***duplication***
                        blank and/or the ***master*** hologram material.
     The optical qualities of the ***PDLC*** material described herein
    provide an improved method of ***duplication*** using single beam
     contact printing regardless of the material comprising the
    hologram. Thus, ***master*** holograms originally recorded using
    highly complex optical geometries (e.g., computer generated holograms) are
     capable of
                 ***duplication*** without the need for multiple beam
```

power/intensity balancing and long recording times. The improved hologram contact printing method described herein works with virtually any type of ***master*** hologram, including both reflection and transmission holograms. replicating vol holograms Holography ***Polymer*** - ***dispersed*** ***liquid*** ***crystals*** (system and method for replicating vol. holograms) THERE ARE 136 CITED REFERENCES AVAILABLE FOR THIS RECORD RE.CNT 136 (1) Akashi; US 5354498 A 1994 CAPLUS (2) Amako; US 5682214 A 1997 CAPLUS (3) Anderson; US 5136666 A 1992 (4) Ando; US 5330264 A 1994 (5) Ando; US 5648857 A 1997 (6) Anon; EP 0087281 a 1983 (7) Anon; JP 60189729 A 1985 (8) Anon; JP 01-068784 a 1989 (9) Anon; JP 03-188479 a 1991 (10) Anon; WO 9727519 1997 CAPLUS (11) Anon; EP 0856765 A1 1998 CAPLUS (12) Anon; EP 0856766 A2 1998 CAPLUS (13) Anon; EP 0856768 A2 1998 CAPLUS (14) Anon; EP 0867749 A2 1998 (15) Anon; JP 10319237 1998 CAPLUS (16) Anon; WO 9804650 a 1998 CAPLUS (17) Anon; WO 9909440 1999 (18) Avant; US 5047039 A 1991 (19) Barak; US 4930674 A 1990 (20) Baues; US 4003629 A 1977 (21) Baues; US 4006963 A 1977 (22) Benton, S; SPIE 1979, V212, P2 (23) Benton, S; SPIE 1980, V215, P156 (24) Bischel; US 5544268 A 1996 (25) Bjelkhagen; US 5014709 A 1991 (26) Bjelkhagen, H; Applied Optics 1992, V31(8), P1041 (27) Bowley, C; Mol Cryst Liq 1999, V331, P209 (28) Brandstetter; US 5547786 A 1996 (29) Brumm; US 3758186 A 1973 (30) Buchkremer; US 5734485 A 1998 (31) Chang; US 4818045 A 1989 (32) Coates; US 5323251 A 1994 CAPLUS (33) Crawford; US 5875012 A 1999 CAPLUS (34) Crawford, G; SID International Symposium Digest of Applications Papers 1996, P99 (35) Crockard; US 5174276 A 1992 (36) Cushman; US 4983176 A 1991 (37) Damask; US 5915051 A 1999 (38) Deacon; US 5488681 A 1996 (39) Dejule; US 5363228 A 1994 (40) Dickson; US 5272550 A 1993 (41) Doane; US 4688900 A 1987 (42) Doane; US 5240636 A 1993 CAPLUS (43) Doane; US 5384067 A 1995 CAPLUS (44) Doane; US 5695682 A 1997 CAPLUS (45) Domash; US 5937115 A 1999 (46) Doyle; US 5003386 A 1991 (47) Faris; US 5680233 A 1997 CAPLUS (48) Fergason; US 4810063 A 1989 (49) Fergason; US 4856876 A 1989 (50) Gambogi; US 5930011 A 1999 CAPLUS (51) Goosen; US 4018228 A 1977 (52) Grayzel; US 4809713 A 1989 (53) Gunjima; US 4818070 A 1989 (54) Haines; US 4832445 A 1989 (55) Hall; US 5471326 A 1995 (56) Haugh; US 3658526 A 1972 CAPLUS (57) Healey; US 4923269 A 1990 (58) Heynderickx; US 5210630 A 1993 (59) Hirai; US 5235445 A 1993 CAPLUS

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ST

IT

RE

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L3
     ANSWER 2 OF 5 CAPLUS COPYRIGHT 2005 ACS on STN
AN
     1998:483253 CAPLUS
     129:189970
DN
ED
     Entered STN: 04 Aug 1998
ΤI
     Effect of molar mass of an epoxy oligomer on the phase separation in epoxy
             ***polymer***
                             ***dispersed***
                                                   ***liquid***
       ***crystals***
     Siddiqi, Humaira Masood; Dumon, Michel; Pascault, Jean Pierre
ΑU
     Laboratoire des Mat riaux Macromoleculaires UMR 5627 CNRS, Institut
CS
     National des Sciences Appliquees, Villeurbanne, F- 69 621, Fr.
     Journal of Materials Chemistry (1998), 8(8), 1691-1695
SO
     CODEN: JMACEP; ISSN: 0959-9428
PB
     Royal Society of Chemistry
DT
     Journal
     English
LA
CC
     37-5 (Plastics Manufacture and Processing)
     Section cross-reference(s): 75
       ***Polymer***
AB
                         ***dispersed***
                                             ***liq***
                                                        . ***crystals***
    based on epoxy-amine [DGEBA-Jeffamine D400] crosslinked matrixes and a
     nematic liq. crystal, E7, were studied over the course of polymn., i.e. as
     a function of the polymn. conversion. The effect of the mol. wt. of the
     epoxy oligomer on the initial temp.-concn. and the temp.-conversion phase
     diagrams was studied. An increase of the epoxy oligomer mol. wt. greatly
     reduces the initial liq. crystal soly. and brings the cloud point to
     earlier polymn. conversions, which were quantified. Thus the phase sepn.
     is markedly enhanced. The temp.-conversion phase diagrams were
     characterized at two isothermal polymn. temps. for one liq. crystal compn.
     (50 wt.). These diagrams (isotropic-nematic and nematic-isotropic
     transition temps.) obey
                               ***master***
                                              curves when the mol. wt. of the
     epoxy is varied. The size of the liq. crystal droplets decreases when the
    mol. wt. of the epoxy increases. This effect is mainly due to the
    viscosity increase resulting from the oligomer wt. increase. Viscosity
    measurements were made at intervals during polymn.
     epoxy oligomer E7 liq crystal phase; phase sepn liq crystal epoxy
st
ΙT
     Cloud point
     Phase diagram
     Phase separation
     Viscosity'
        (effect of mol. wt. of epoxy oligomer on phase sepn. of epoxy/E7 liq.
        crystal dispersion)
IT
     Epoxy resins, preparation
     RL: PRP (Properties); SPN (Synthetic preparation); PREP (Preparation)
        (effect of mol. wt. of epoxy oligomer on phase sepn. of epoxy/E7 liq.
        crystal dispersion)
     Liquid crystals
        (nematic; effect of mol. wt. of epoxy oligomer on phase sepn. of
        epoxy/E7 liq. crystal dispersion)
IT
     Liquid crystals
        (transitions, nematic-isotropic transition; effect of mol. wt. of epoxy
        oligomer on phase sepn. of epoxy/E7 liq. crystal dispersion)
IT
     63748-28-7, E7.
     RL: PRP (Properties)
        (effect of mol. wt. of epoxy oligomer on phase sepn. of epoxy/E7 liq.
        crystal dispersion)
     110302-44-8P, DGEBA-Jeffamine D400 copolymer
     RL: PRP (Properties); SPN (Synthetic preparation); PREP (Preparation)
        (effect of mol. wt. of epoxy oligomer on phase sepn. of epoxy/E7 liq.
        crystal dispersion)
RE.CNT
              THERE ARE 17 CITED REFERENCES AVAILABLE FOR THIS RECORD
       17
RE

    Aklonis, J; Introduction to polymer viscoelasticity 1982

(2) Borrajo, J; Polymer 1998, V39, P845 CAPLUS
(3) Dusek, K; J Polym Sci, Polym Symp 1975, V53, P29 CAPLUS
(4) Eloundou, J; Macromolecules 1996, V29, P6907 CAPLUS
(5) Eloundou, J; Macromolecules 1996, V29, P6917 CAPLUS
(6) Fox, T; Bull Am Chem Soc 1956, V2, P123
(7) Hirai, Y; SPIE 1990, V1257, P2 CAPLUS
(8) Kim, B; J Polym Sci, Part B: Polym Phys 1995, V33, P707 CAPLUS
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(9) Kyu, T; Mol Cryst Liq Cryst 1996, V287, P27 CAPLUS
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(11) Masood, H; Polymer 1996, V37, P4795
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(17) Williams, R; Adv Polym Sci 1997, V128, P95 CAPLUS
    ANSWER 3 OF 5 CAPLUS COPYRIGHT 2005 ACS on STN
L3
AN
    1997:655031 CAPLUS
    127:353053
DN
    Entered STN: 15 Oct 1997
ED
TI
    Liquid crystal display
IN
    Ikeda, Mitsushi; Fukunaga, Yoko
PA
    Toshiba Corp., Japan
SO
    Jpn. Kokai Tokkyo Koho, 16 pp.
    CODEN: JKXXAF
DT
    Patent
LA
    Japanese
IC
    ICM G02F001-136
    ICS G02F001-1333; G02F001-1343
CC
    74-13 (Radiation Chemistry, Photochemistry, and Photographic and Other
    Reprographic Processes)
FAN.CNT 1
    PATENT NO.
                        KIND
                               DATE
                                           APPLICATION NO.
                                                                  DATE
     _____
                               -----
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                                           -----
                                                                  -----
    JP 09258260
                         A2
                               19971003
                                           JP 1996-66634
                                                                  19960322
PΙ
PRAI JP 1996-66634
                               19960322
CLASS
 PATENT NO.
                CLASS PATENT FAMILY CLASSIFICATION CODES
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                       ______
JP 09258260
                ICM
                       G02F001-136
                ICS
                       G02F001-1333; G02F001-1343
    The title display has contact holes for connecting TFTs and pixel
AB
    electrodes, and an insulation film covered on the exposure regions of the
    pixel electrodes and common electrodes. The liq. crystal display may have
     multiple dye-contg. ***liq*** .
                                         ***crystal*** / ***polymer***
                         layers. The invention can assure good connection and
       ***dispersion***
     offer a simple way for manuf. of the high quality liq. crystal display.
ST
     liq crystal display contact hole; insulation film liq crystal display
IT
    Acrylic polymers, uses
    RL: DEV (Device component use); TEM (Technical or engineered material
    use); USES (Uses)
        (forming insulation film in
                                     ***contact***
                                                     holes for covering
          ***exposure***
                         region of pixel and common electrode for liq. crystal
       display)
IT
    Liquid crystal displays
        (having contact hole for connecting TFTs and pixel electrodes)
IT
     1518-16-7, Tetra cyano quinodimethane
                                            7440-02-0, Nickel, uses
     25233-30-1, Polyaniline
                             30604-81-0, Polypyrrole
    RL: DEV (Device component use); TEM (Technical or engineered material
    use); USES (Uses)
        (coated on contact hole for connecting TFT and pixel electrode)
    ANSWER 4 OF 5 CAPLUS COPYRIGHT 2005 ACS on STN
L3
     1994:521852 CAPLUS
AN
DN
     121:121852
ED
    Entered STN: 03 Sep 1994
TI
    Copier-platen liquid-crystal variable area-mask devices
IN
    Ueno, Osamu; Hiji, Naoki
PA
    Fuji Xerox Co Ltd, Japan
SO
    Jpn. Kokai Tokkyo Koho, 12 pp.
    CODEN: JKXXAF
DT
    Patent
LA
    Japanese
IC
     ICM G02F001-1333
     ICS G02F001-13; G02F001-1343; G03B027-62; G03G015-00; H04N001-04
ICA
    G03G015-04
CC
    74-13 (Radiation Chemistry, Photochemistry, and Photographic and Other
    Reprographic Processes)
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Section cross-reference(s): 73
FAN.CNT 1
                  KIND DATE APPLICATION NO. DATE
    PATENT NO.
                    A2 19940225 JP 1993-135208 19930514
PI JP 06051295
PRAI JP 1992-166703
                    ----
                    A1 19920603
CLASS
PATENT NO. CLASS PATENT FAMILY CLASSIFICATION CODES
              ----
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JP 06051295 ICM G02F001-1333
              ICS
                    G02F001-13; G02F001-1343; G03B027-62; G03G015-00;
                    H04N001-04
              ICA G03G015-04
    The device comprises: a matrix array of electrooptical ***polymer*** -
AB
      for driving the individual microcells for forming various transparent
    patterns. The device is suited for use as a variable mask on the platen
    of a ***copying*** machine.
ST
    lig crystal microcell array platen mask
    Optical imaging devices
IT
       (electrooptical ***liq*** .- ***crystal*** , ***polymer*** -
         ***dispersed*** microcell array, in variable-area platen masks, for
       copiers)
IT
    25038-59-9, Polyethylene terephthalate, uses
    RL: USES (Uses)
       microcell arrays, as substrate)
L3
    ANSWER 5 OF 5 CAPLUS COPYRIGHT 2005 ACS on STN
    1992:613850 CAPLUS
ΑN
DN
    117:213850
    Entered STN: 28 Nov 1992
ED
    Composites of thermoplastic and liquid crystal polymers and their
TI
    manufacture
IN
    Coffey, Gerald P.; Perec, Elena S.; Melamud, Lucy
PA
    BP America, Inc., USA
    Eur. Pat. Appl., 24 pp.
SO
    CODEN: EPXXDW
DT
    Patent
LA
    English
IC
    ICM C08L101-00
    ICS C08L067-03
CC
    37-6 (Plastics Manufacture and Processing)
    Section cross-reference(s): 75
FAN.CNT 1
                 KIND DATE APPLICATION NO. DATE
    PATENT NO.
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    EP 499387 A2 19920819 EP 1992-300827
EP 499387 A3 19921223
                                                         19920131
PΙ
       R: AT, BE, CH, DE, DK, ES, FR, GB, GR, IT, LI, LU, MC, NL, PT, SE
    CA 2060494 AA 19920814 CA 1992-2060494 19920131
CN 1067913 A 19930113 CN 1992-101629 19920212
                                     CN 1992-101629
CN 1067913 A 19930113 CN 1992-101629
JP 05214253 A2 19930824 JP 1992-26416
PRAI US 1991-654853 A 19910213
                                                         19920213
CLASS
 PATENT NO. CLASS PATENT FAMILY CLASSIFICATION CODES
 EP 499387 ICM C08L101-00 ICS C08L067-03
    Chem resistant and mech. strong composites contg. .ltoreq.2% ***liq***
AB
       thermoplastic resin are manufd. by dispersing .gtoreq.2% solid LCP into
    molten thermoplastic and dilg. the ***masterbatch*** with addnl.
    thermoplastic polymer. Moldings, prepd. from 90/10 high-d. polyethylene
    (HDPE) - Vectra A950 (I, liq. - cryst. polyester) ***masterbatch*** with
    subsequent diln. by HDPE to I content 1%, had tensile strength 3518.9 psi,
    yield elongation 11.19%, break elongation .gtoreq.995% (for 3 of 6
    samples), and good chem resistance.
ST
    polyethylene liq cryst polyester blend; chem resistance polyethylene
    polyester blend; dispersion liq cryst polyester polyethylene
IT
    Impact-resistant materials
       (blends of liq.-cryst. polyesters and thermoplastic polymers as, with
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good mech. strength and chem resistance)
     Acrylic polymers, uses
IT
    Polyamides, uses
     RL: USES (Uses)
        (liq.-cryst. polyester blends with, with good mech. strength and chem
        resistance)
    Plastics, molded
ΙT
     RL: USES (Uses)
        (liq.-cryst. polyester blends, with good mech. strength and chem
        resistance)
     Polyesters, miscellaneous
     RL: MSC (Miscellaneous)
        (liq.-cryst., blends with thermoplastic polymers, with good mech.
        strength and chem resistance)
     Alkenes, polymers
     RL: USES (Uses)
        (polymers, liq.-cryst. polyester blends with, with good mech. strength
        and chem resistance)
     Chemically resistant materials
IT
        (solvent-resistant, blends of liq.-cryst. polyesters and thermoplastic
        polymers as, with good mech. strength)
ΙT
     Liquid crystals, polymeric
        (thermotropic, polyester, blends with thermoplastic polymers, with good
        mech. strength and chem resistance)
                                              81843-52-9, Vectra A 950
     25822-54-2, Rodrun
                          31072-56-7, Xydar
IT
    RL: USES (Uses)
        (blends with thermoplastic polymers, with good mech. strength and chem
        resistance)
     9003-07-0, Polypropylene
     RL: USES (Uses)
        (liq.-cryst. polyester blends with 5C08, with good mech. strength and
        chem resistance)
     9002-88-4, Polyethylene
                               9003-53-6
                                           9010-79-1, Ethylene-propylene
     copolymer 25068-26-2, Poly(4-methyl-1-pentene)
                                                        26221-73-8, Dowlex 2045
     108771-80-8, Barex 210
     RL: USES (Uses)
        (liq.-cryst. polyester blends with, with good mech. strength and chem
        resistance)
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     FILE 'CAPLUS' ENTERED AT 15:40:03 ON 16 AUG 2005
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              5 S (COPY? OR COPIED OR MASTER? OR (CONTACT(5A)EXPOS?)) AND L1
L2
              5 S (COPY? OR COPIED OR MASTER? OR DUPLICAT? OR (CONTACT(5A) EXPOS
L3
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CA SUBSCRIBER PRICE
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